

# RJK0603DPN-E0

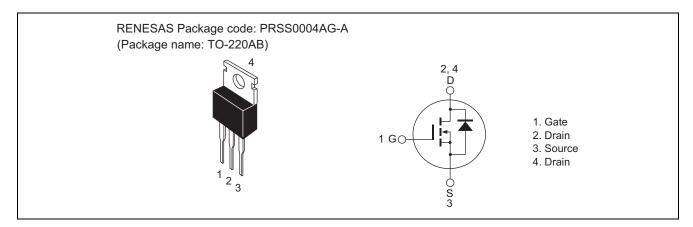
N-Channel MOS FET 60 V, 80 A, 5.2 m $\Omega$ 

R07DS0654EJ0200 Rev.2.00 Aug 24, 2012

#### **Features**

- High speed switching
- Low drive current
- Low on-resistance  $R_{DS(on)} = 4.1 \text{ m}\Omega \text{ typ.}$  (at  $V_{GS} = 10 \text{ V}$ )
- Package TO-220AB

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	60	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	80	А
Drain peak current	I <sub>D (pulse)</sub> Note1	240	А
Body-drain diode reverse drain current	I <sub>DR</sub>	80	А
Avalanche current	I <sub>AP</sub> Note2	40	А
Avalanche energy	E <sub>AS</sub> Note2	120	mJ
Channel dissipation	Pch Note3	125	W
Channel to case thermal impedance	θch-c	1.0	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at L = 100  $\mu H$  , Tch = 25°C, Rg  $\geq 50\Omega,$
- 3. Tc = 25°C

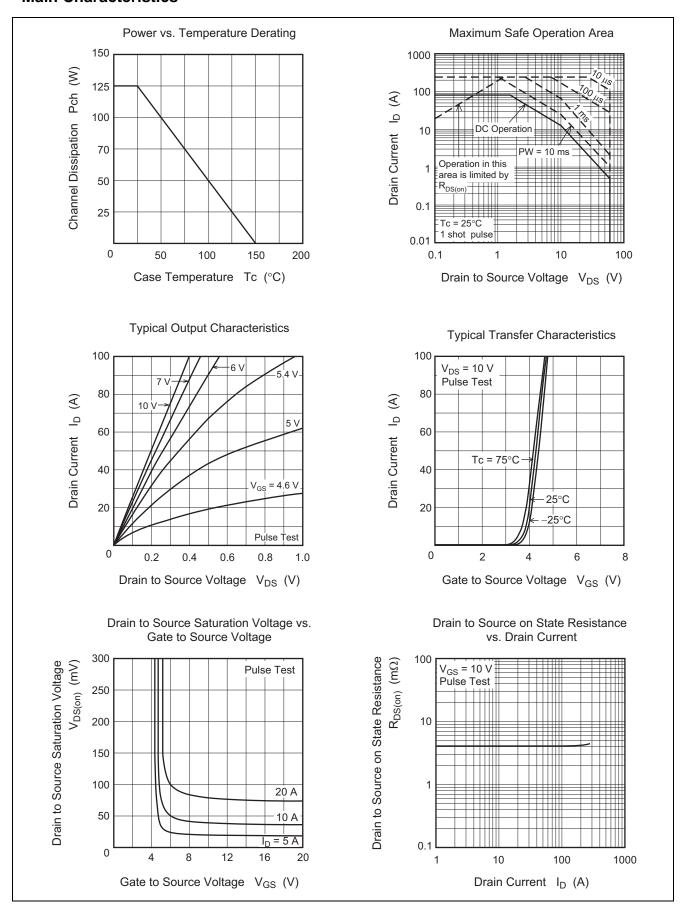
## **Electrical Characteristics**

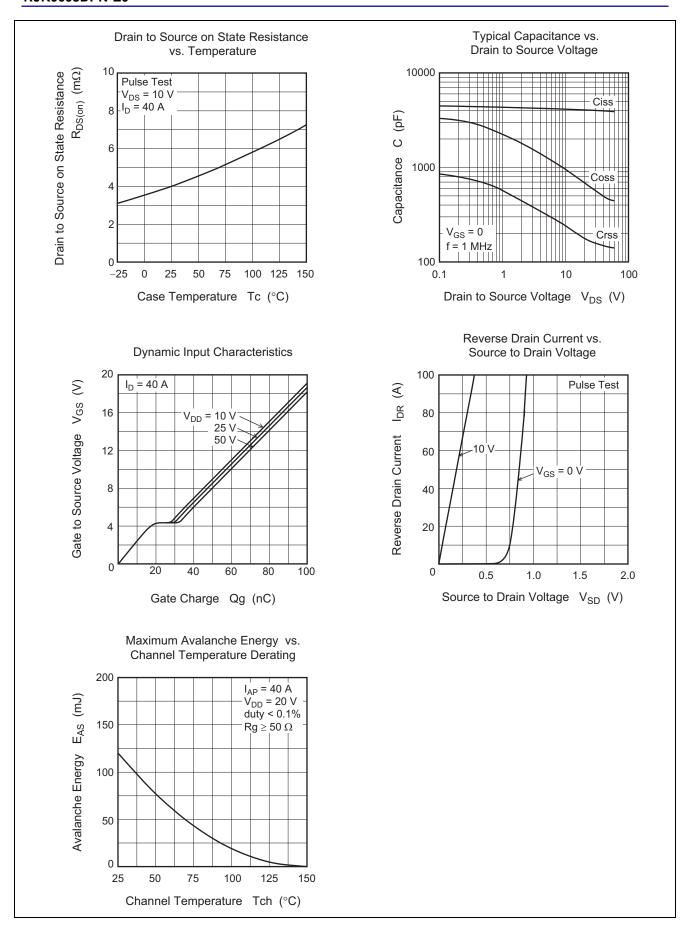
 $(Ta = 25^{\circ}C)$ 

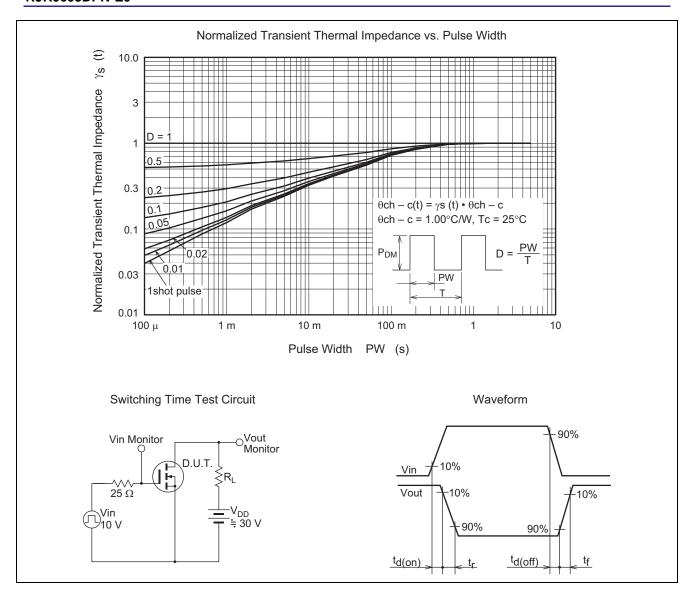
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{mA}, V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>		4.1	5.2	mΩ	$I_D = 40 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance						
Forward transfer admittance	y <sub>fs</sub>		80	_	S	$I_D = 40 \text{ A}, V_D = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss		4150	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss		950	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	230	_	pF	
Gate Resistance	Rg	_	1.6	_	Ω	
Total gate charge	Qg	_	57	_	nC	V <sub>DD</sub> = 25 V
Gate to source charge	Qgs		20	_	nC	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 40 A
Gate to drain charge	Qgd		10	_	nC	
Turn-on delay time	t <sub>d(on)</sub>		30	_	ns	V <sub>GS</sub> = 10 V
Rise time	t <sub>r</sub>		12	_	ns	$\begin{split} I_D &= 40 \text{ A} \\ V_{DD} &\cong 30 \text{ V} \\ Rg &= 4.7  \Omega \end{split}$
Turn-off delay time	$t_{d(off)}$		60	_	ns	
Fall time	t <sub>f</sub>	_	13	_	ns	
Body-drain diode forward voltage	$V_{DF}$	_	0.85	1.5	V	$I_F = 80 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	50	_	ns	$I_F = 80 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

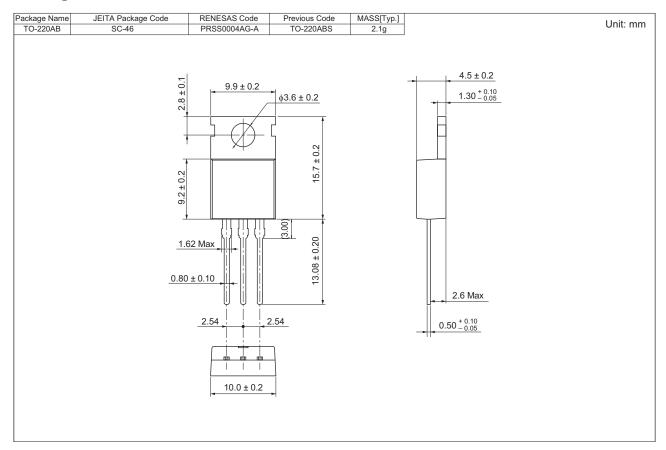
## **Main Characteristics**







## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK0603DPN-E0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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